



VS 高压耐硫厚膜贴片电阻规格书-VS 系列

Approval Specification for High Voltage Anti-Sulfuration Thick Film Chip Resistors -
Type VS

规格书

SPECIFICATION

丽智电子（南通）有限公司

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1. 范围 (scope) :

1.1 适用于本公司所生产的无铅、无卤之高压耐硫厚膜贴片电阻 VS 系列

This specification applies to High Voltage Anti-Sulfuration thick film chip resistors which meet requirements of Pb free and halogen free.

1.2 本公司的无铅产品指的贴片电阻端电极无铅，而存在于电阻层的玻璃中的符合 RoHS 豁免条款。

There no lead exists in terminal of resistor, and lead which exist in glass of resistor layer meets RoHS exemption.

2. 产品料号 (part number) :

2512 1W 1% 510K






VS2512F15103G

VS	<u>2512</u>	<u>F</u>	<u>1</u>	<u>5103</u>	<u>G</u>
↓	↓	↓	↓	↓	↓
类型(Type) VS: 高压耐硫厚膜贴片电阻 (high Voltage Anti-Sulfuration thick film chip resistors)	尺寸(Size) 2512	公差 Tolerance F=±1%	额定功率 Rated Power 1= 1W	阻值 Resistance value ±1% : 5103=510KΩ	包装代码 Packing Code G= reel (卷装) V= bulk (散料) S= Double Standard Quantity (两倍卷盘标准包装量)

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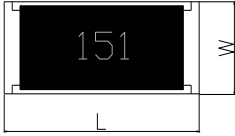
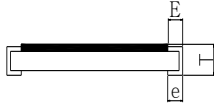
3. 电阻本体字码标示(Marking on the Resistor's Body):

<p>※ 公差±5%的产品，以三字码标示，前两位表示阻值的有效数字，最后一位表示 10 的乘幂 $\pm 5\%$ tolerance product: the marking is 3 digits, the first 2 digits are significant figures of resistance value and the 3rd one denotes the power number of 10, (10^x)</p> <p>※ 公差±0.1%±0.5%及±1%的产品，以四字码标示，前三位表示阻值的有效数字，最后一位表示 10 的乘幂 $\pm 0.1\%$、$\pm 0.5\%$ and $\pm 1\%$ tolerance product: the marking is 4 digits, the first 3 digits are significant figures of resistance value and the 4th one denotes the power number of 10, (10^x)</p> <p>※ 0 欧姆产品，采用 000 三位代码标示。 $0\ \Omega$ Products, use 000 3digits code to indicate the resistance value.</p>		$472=47\times 10^2=4.7K\ \Omega$
		$10\ \Omega$ 以下标示: $5R6=5.6\ \Omega$ Below $10\ \Omega$: $5R6=5.6\ \Omega$
		$4992=499\times 10^2=49.9K\ \Omega$
		$100\ \Omega$ 以下标示: $6R81=6.81\ \Omega$ Below $100\ \Omega$: $6R81=6.81\ \Omega$
		$000=0\ \Omega$

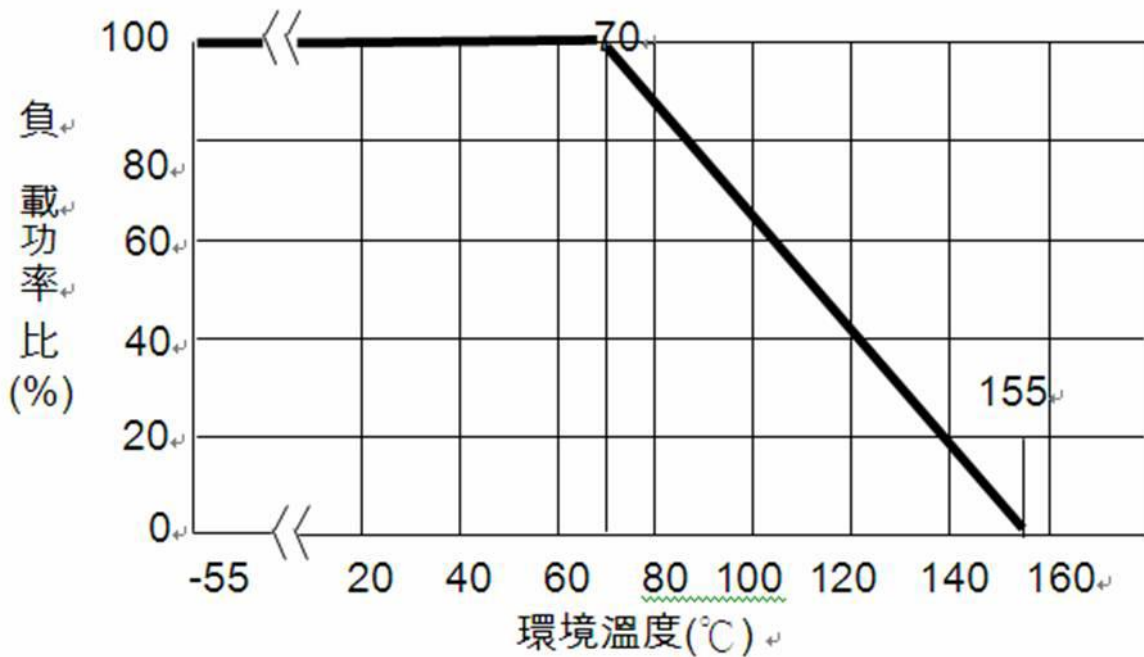
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4. 尺寸 (dimension) :

尺寸 dimension					单位 (unit) : mm	
型别 (Type)	L	W	T	E	e	
VS2512	6.25±0.20	3.10±0.20	0.55±0.15	0.85±0.25	0.95±0.25	

5. 功率衰减曲线 (Derating Curve) :



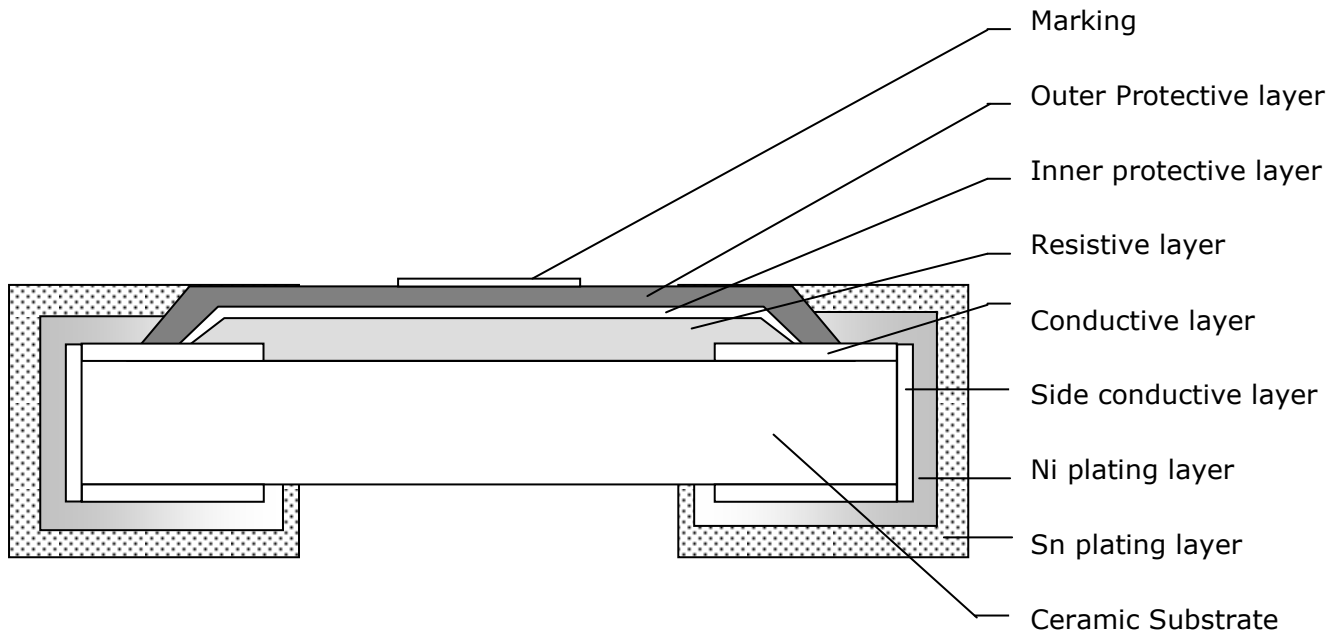
工作温度范围 (Operating Temperature Range) : -55°C~+155°C

储存条件 (storage condition) : 5~30°C, 30~75%RH.

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6.电阻结构（Construction）：



No.	结构 construction	主要材料 Major material
1	陶瓷基板 Ceramic substrate	三氧化二铝 Al ₂ O ₃
2	银电极 Conductive layer	银 Ag
3	侧电极 Side conductive layer	镍铬合金 NiCr
4	阻体层 Resistive layer	氧化钌+玻璃 RuO ₂ + glass
5	内保护层 Inner protective layer	玻璃 Glass
6	外保护层 Outer Protective layer	环氧树脂 Epoxy
7	文字 Marking	环氧树脂 Epoxy
8	镍电极 Ni plating layer	镍 Ni
9	锡电极 Sn plating layer	雾锡 Matte Tin

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7. 阻值范围 (resistance range) :

型别 Type	阻值范围 Resistance Range
	1%
VS2512	510K Ω

8. 电气特性 (electrical characteristics) :

型别 Type	额定功率 Rated power	最大工作 电压 Max Working Voltage	绝缘耐压 Dielectric Withstanding Voltage
VS2512	1W	1600V	710V

备注 (remark) :

※ 额定电压计算公式 (The rated voltage is calculated by the following formula) :

$$E = \sqrt{RP}$$

E: 额定电压 (Rated Voltage) (V)

P: 额定功率 (Rated Power) (W)

R: 电阻阻值 (Resistance) (ohm)

※ 如果计算出的电压超过此型别的最大工作电压, 则此型别的最大工作电压为此电阻的额定电压。

In case the value calculated by the formula exceed the maximum working voltage as above table 8, the maximum working voltage shall be regarded as rated voltage.

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9.性能信赖性测试 (Performance Reliability Test Methods)

内容 Item	测试方法 Test Methods	测试条件 Test Conditions	规格 Specification
温度系数 Temperature Coefficient	JIS C 5201 4.8	$TCR = (R - R_0) / (t - t_0) R_0 \times 10^6$ (ppm) R_0 电阻在室温下的阻值(resistance at room temperature) R 电阻在 125°C 或 -55°C 下的阻值(resistance at 125°C or -55°C) t_0 室温(room temperature) t 测试温度 (test temperature 125°C or -55°C)	±50 PPM/°C
焊锡性 Solderability	JIS C 5201 4.17	沾助焊剂后浸入锡炉，锡炉温度 245±5°C，时间 3±0.5 秒 Dip the terminal in a flux and then dip into a soldering bath at 245±5°C for 3±0.5sec.	最少 95% 面积上锡 (Min 95% coverage)
绝缘电阻 Insulation resistance	JIS C 5201 4.6	电阻本体上加载绝缘耐压 60±5 秒后，测量绝缘阻抗 Applied the dielectric withstanding voltage on the center of body for 60±5seconds. Then measure insulation resistance	>10G Ω
绝缘耐压 Dielectric withstanding voltage	JIS C 5201 4.7	电阻本体上加载绝缘耐压 60±5 秒。 Applied the dielectric withstanding voltage on the center of body for 60±5seconds.	无击穿、飞弧及可见机械性损伤 No evidence of flashover, mechanical damage arcing or insulation breakdown

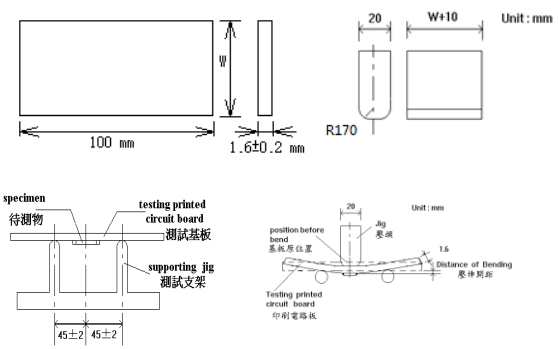
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内容 Item	测试方法 Test Methods	测试条件 Test Conditions	规格 Specification
短时间过负荷 Short-time overload	JIS C 5201 4.13	加载 2.5 倍的额定电压, 时间 5 秒后测量试验前后的阻值变化率。 Applied 2.5 times of rated voltage for 5 second. Measure the variation of resistance. $\Delta R\% = \frac{R_2 - R_1}{R_1} * 100 \text{-----} (\%)$ R1 = 试验前阻值(resistance before test) R2 = 试验后阻值(resistance after test)	±(1.0%+0.05 Ω) Max
抗焊锡热 Resist to soldering heat	JIS C 5201 4.18	沾助焊剂后浸入锡炉, 锡炉温度 260±5℃, 时间 10±0.5 秒, 测量试验前后的阻值变化率。 Dip the terminal in a flux and then dip into a soldering bath at 260±5℃ for 10±0.5sec. Measure the variation of resistance. $\Delta R\% = \frac{R_2 - R_1}{R_1} * 100 \text{-----} (\%)$ R1 = 试验前阻值(resistance before test) R2 = 试验后阻值(resistance after test)	±(1.0%+0.05 Ω) Max

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内容 Item	测试方法 Test Methods	测试条件 Test Conditions	规格 Specification
端子弯曲 Terminal bending	JIS C 5201 4.33	<p>电阻焊接在测试板上进行弯折,弯折保持时间 20±1 秒, 尺寸弯曲 2^{+0.2}%mm; 量测试前后阻值变化率</p> <p>Specimen shall be mounted on test board, then bend the board and maintained for 20±1s. 2^{+0.2}% mm which size larger. Measure the variation of resistance.</p> <p style="text-align: center;">测试板 (test board) 压头 (jig)</p> <div style="text-align: center;">  </div> $\Delta R\% = \frac{R_2 - R_1}{R_1} * 100 \text{-----} (\%)$ <p>R1 = 试验前阻值(resistance before test) R2 = 试验后阻值(resistance after test)</p>	±(1.0%+0.05 Ω) Max

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内容 Item	测试方法 Test Methods	测试条件 Test Conditions	规格 Specification
温度循环 Temperature Cycling	JIS C 5201 4.19	电阻放入温度循环机中，温度 155±2℃至-55±3℃，共 5 个循环。 量测试验前后阻值变化率。 Put specimen in a chamber which temperature can be changed to 155±2℃ or -55±3℃, repeated 5 times. Measure the variation of resistance. $\Delta R\% = \frac{R_2 - R_1}{R_1} * 100 \text{-----} (\%)$ R1 = 试验前阻值(resistance before test) R2 = 试验后阻值(resistance after test)	±(2.0%+0.05 Ω) Max
耐湿特性 Humidity	JIS C 5201 4.24	电阻放入恒温恒湿箱，温度 40±2℃，湿度 90~95 %RH;通电额定电压 1.5 小时，断电 0.5 小时；重复通断电至试验时间 1000 ⁺⁴⁸ /0 小时。 量测试验前后阻值变化率。 Put the specimen in a chamber at 40±2℃ temperature and 90~95% relative humidity, then applied rated voltage for 1.5H and rested for 0.5H repeatedly till total test time is 1000 ⁺⁴⁸ /0.. Measure the variation of resistance. $\Delta R\% = \frac{R_2 - R_1}{R_1} * 100 \text{-----} (\%)$ R1 = 试验前阻值(resistance before test) R2 = 试验后阻值(resistance after test)	±(2.0%+0.05 Ω) Max

内容 Item	测试方法 Test Methods	测试条件 Test Conditions	规格 Specification
负荷寿命 Load life	JIS C 5201 4.25.1	电阻放入恒温箱中，温度 70±2℃，ON TIME:1.5H，OFF TIME:0.5H，通电额定电压 1000 ⁺²⁴ /0 小时，量测试验前后阻值变化率。 Put the specimen in a chamber at 70±2℃ temperature, ON TIME:1.5H, OFF TIME:0.5H, and applied rated voltage for 1000 ⁺²⁴ /0.H. Measure the variation of resistance.	±(2.0%+0.05 Ω) Max

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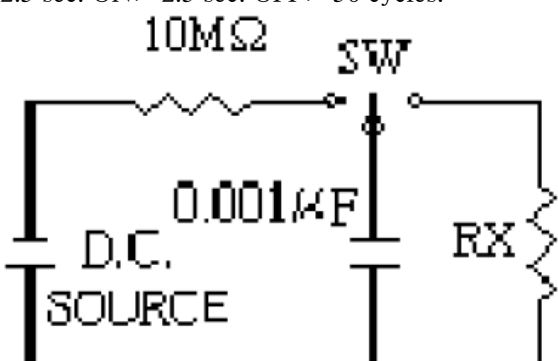
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		$\Delta R\% = \frac{R_2 - R_1}{R_1} * 100 \text{-----} (\%)$ <p>R1 = 试验前阻值(resistance before test) R2 = 试验后阻值(resistance after test)</p>	
温湿循环 Moisture resistance	MIL-STD-202 METHOD 106	<p>25 ° C~65 ° C,90~100%RH, 2.5 小时 ; 65 ° C 90~100%RH, 3小时; 65°C~25°C,80~100%RH,2.5 小时,10个循环,试验结束24±4小时后进行测试.</p> <p>25 ° C~65 ° C,90~100%RH, 2.5H; 65 ° C 90~100%RH, 3H; 65°C~25°C 80~100%RH, 2.5H, 10 cycles, Measurement at 24±4 hours after test conclusion.</p> $\Delta R\% = \frac{R_2 - R_1}{R_1} * 100 \text{-----} (\%)$ <p>R1 = 试验前阻值(resistance before test) R2 = 试验后阻值(resistance after test)</p>	±(2.0% +0.05 Ω) Max

内容 Item	测试方法 Test Methods	测试条件 Test Conditions	规格 Specification
高温储存 High Temperature Exposure(Storage)	MIL-STD-202 METHOD 108	<p>155°C下放置 1000h,不加载功率, 试验结束 24±4 小时后进行测试.</p> <p>1000 hrs. @ T=155 °C . Unpowered. Measurement at 24 ± 4 hours after test conclusion</p> $\Delta R\% = \frac{R_2 - R_1}{R_1} * 100 \text{-----} (\%)$ <p>R1 = 试验前阻值(resistance before test) R2 = 试验后阻值(resistance after test)</p>	±(1.00%+0.05 Ω) Max
ESD 试验 ESD test	AEC-Q200-002	<p>加载规定静电电压2次/间隔1秒, 0201/0402规格:0.5KV, 0603规格:1KV, 其它规格2KV: 0201/0402:0.5KV, 0603: 1.0KV, Other:2KV, 2times/1s</p> $\Delta R\% = \frac{R_2 - R_1}{R_1} * 100 \text{-----} (\%)$ <p>R1 = 试验前阻值(resistance before test) R2 = 试验后阻值(resistance after test)</p>	±(3.0%+0.05 Ω) Max

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内容 Item	测试方法 Test Methods	测试条件 Test Conditions	规格 Specification
抗硫化试验 Sulfuration test	ANSI/EIA-977	方法一：在玻璃容器底部的培养皿上铺满10mm厚的硫粉，烘烤105℃，750hrs 方法二：切削油:硫粉=96.5:3.5，温度105℃，100H; 预处理：前后先经历3次回流焊+100次温冲 Method 1: cover the tray or base of the chamber with a bed of sulfur to 10 mm depth minimum, bake at 105℃, 750hrs Method 2: cutting oil: sulfur powder =96.5:3.5, temperature 105℃, 100H; Pretreatment: before and after three reflow soldering +100 thermal shock $\Delta R\% = \frac{R_2 - R_1}{R_1} * 100 \quad (\%)$ R1 = 试验前阻值(resistance before test) R2 = 试验后阻值(resistance after test)	±(3.0% +0.05 Ω) Max
脈衝 Pulse withstanding voltage		在下图的电路中重复放电循环， 2.5 sec. ON， 2.5 sec. OFF， 50 cycles. 	±(20% +0.05 Ω) Max

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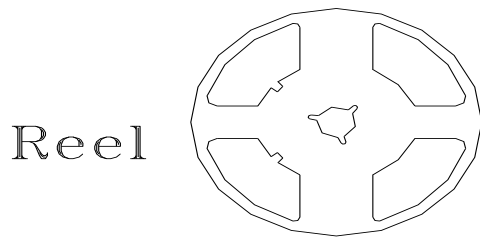
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10. 包装规格 (Tapping Specification)

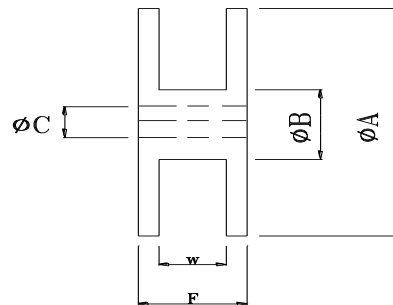
10.1 卷盘尺寸 (reel dimension)

尺寸 Dimensions		A	B	C	F	W
VS2512	mm	178±2.0	60.0±1.0	13.5±0.5	15.4±1.0	13.0±0.3
	Inch	7.008±0.079	2.362±0.039	0.531±0.020	0.606±0.039	0.512±0.012

※ 备注 (Remark) : 2512 每卷 4,000 pcs
 2512 Quantity per Reel 4,000 pcs/Reel



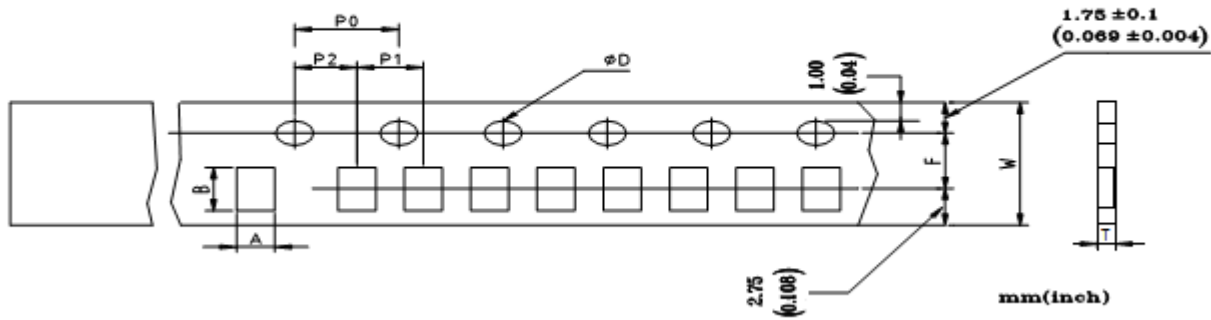
Standard Quantity per Reel
 5,000 pcs/Reel



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10.2 包装尺寸 (packing dimension)



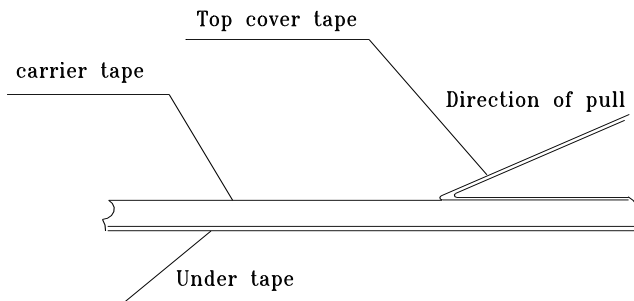
Unit: mm

Dimensions	A	B	D	F	P0	P1	P2	W	T
VS2512	3.40±0.10	6.60±0.10	1.50 ^{±0.1} _{0.0}	5.50±0.05	4.00±0.10	4.00±0.10	2.00±0.05	12.0±0.10	1.0±0.07

11. 上胶带剥离力测试 (Peel force of top cover tape)

上胶带以 200mm/分钟的速度，沿 165~180 度角的方向进行剥离，如下图所示。纸带的剥离力范围为 10g~70g；载带的剥离力范围为 15~80g。

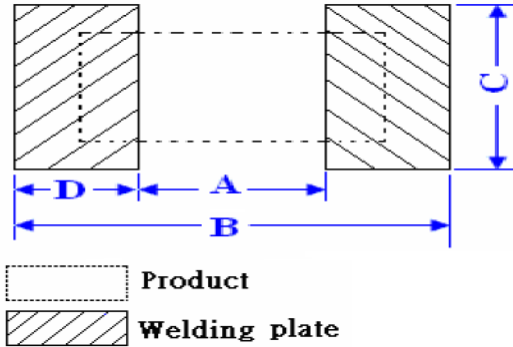
The top cover tape is pulled at a speed of 200 mm/min with the angle between the tape during peel and the direction of unreeling maintained at 165 to 180 degree as following picture. The peel force of paper carrier tape shall be 0.1N to 0.7N(10 to 70 g), the peel force of plastic carrier tape shall be 0.15N to 0.80N (15 to 80 g)



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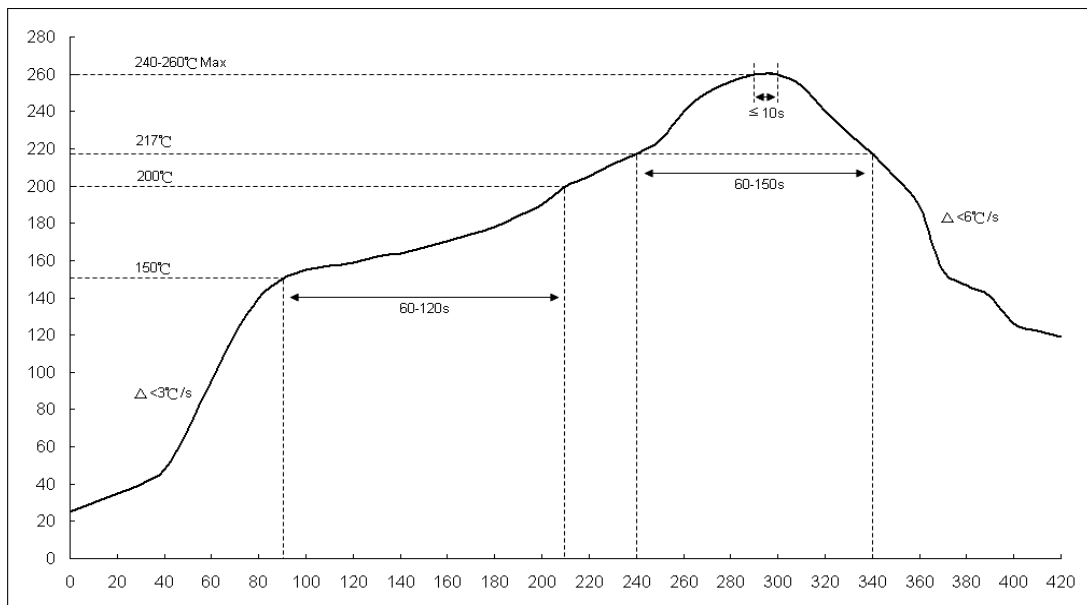
12. 焊盘尺寸 (Recommended land patterns):



Type \ Land pattern	Dimensions (mm)			
	A	B	C	D
VS2512	3.60~4.00	7.60~8.60	2.30~3.50	2.05~2.25

13. 焊接 (soldering)

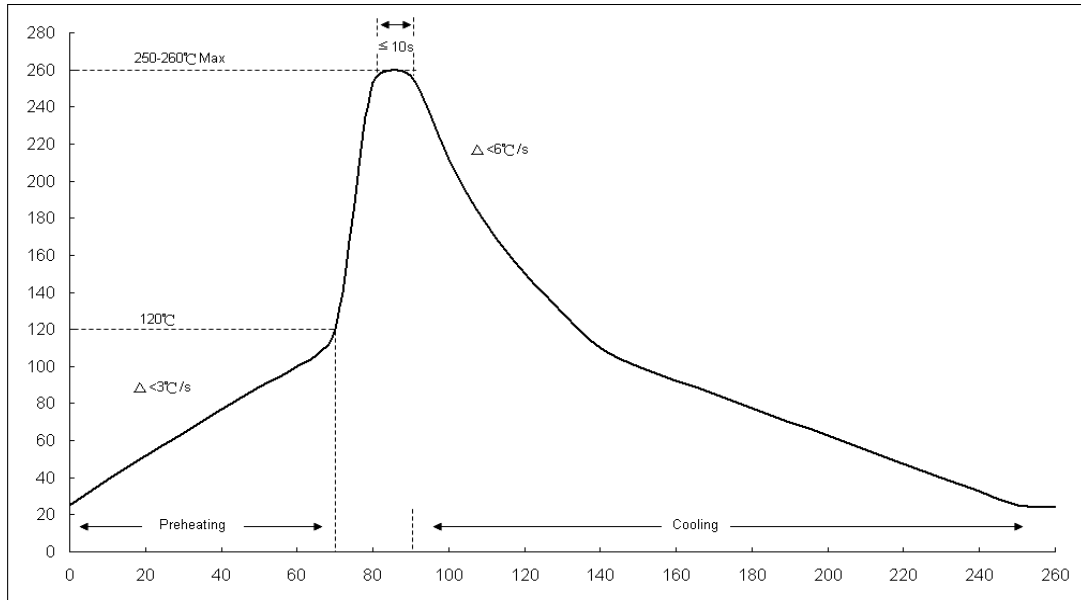
13.1 建议回流焊曲线 (Recommend reflow soldering profile)



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13.2 建议波峰焊曲线 (Recommend wave soldering profile)



13.3 手工焊温度 (hand soldering temperature)

烙鐵溫度 $350\pm 10^{\circ}\text{C}$ 3 秒之內，避免烙鐵接觸電阻本體

The iron temperature is $350\pm 10^{\circ}\text{C}$, hand soldering time less than 3S. Avoid solder iron tip direct touch the components body.